NSN 5961-01-075-6832

No Fiig: A110a0

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-075-6832 **Inclosure Material:** Metal **Overall Length:** 0.780 inches **Overall Diameter:** 1.900 inches **Mounting Facility Quantity: Mounting Method:** Threaded stud **Features Provided:** Hermetically sealed case **Thread Size:** 0.250 inches **Semiconductor Material:** Silicon **Voltage Rating In Volts Per Characteristic:** 7500.0 reverse voltage, peak **Current Rating Per Characteristic:** 150.00 amperes peak forward surge current **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius junction **Test Data Document:** 49956-spa-v-30302 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Thread Series Designator:** Unf **Terminal Type And Quantity:** 1 threaded stud and 1 case Shelf Life: N/a **Unit Of Measure: Demilitarization:**